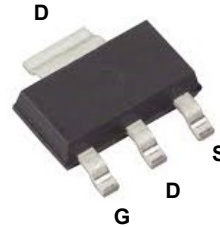
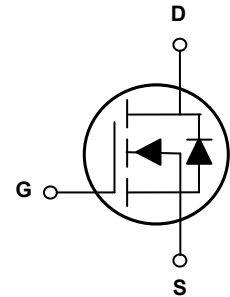


Main Product Characteristics

$V_{(BR)DSS}$	60V
$R_{DS(ON)}$	32m Ω (Typ.)
I_D	5A



SOT-223



Schematic Diagram

Features and Benefits

- Advanced MOSFET process technology
- Ideal for high efficiency switched mode power supplies
- Low on-resistance with low gate charge
- Fast switching and reverse body recovery



Description

The GSFL6046 utilizes the latest techniques to achieve high cell density and low on-resistance. These features make this device extremely efficient and reliable for use in high efficiency switch mode power supplies and a wide variety of other applications.

Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Max.	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-to-Source Voltage	V_{GS}	±20	V
Continuous Drain Current, @ Steady-State (T _A =25°C) ¹	I_D	5	A
Continuous Drain Current, @ Steady-State (T _A =70°C)		3.5	A
Pulsed Drain Current ²	I_{DM}	20	A
Power Dissipation (T _A =25°C)	P_D	27	W
Linear Derating Factor (T _A =25°C)		0.22	W/°C
Single Pulse Avalanche Energy ³	E_{AS}	14	mJ
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	4.63	°C/W
Thermal Resistance, Junction-to-Ambient (PCB Mounted, Steady-State) ⁴	$R_{\theta JA}$	65	°C/W
Operating Junction and Storage Temperature Range	T_J/T_{STG}	-55 to +150	°C

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
On / Off Characteristics						
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	60	-	-	V
Drain-to-Source Leakage Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$	-	-	1	μA
		$T_J=125^\circ\text{C}$	-	-	50	
Gate-to-Source Forward Leakage	I_{GSS}	$V_{GS}=20V$	-	-	100	nA
		$V_{GS}=-20V$	-	-	-100	
Static Drain-to-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=5A$	-	32	46	m Ω
		$V_{GS}=4.5V, I_D=4A$	-	38	50	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.1	1.6	2.8	V
Forward Transconductance	g_{fs}	$V_{DS}=10V, I_D=4A$	-	6	-	S
Dynamic and Switching Characteristics						
Input Capacitance	C_{iss}	$V_{GS}=0V, V_{DS}=30V,$ $f=1\text{MHz}$	-	1179	-	pF
Output Capacitance	C_{oss}		-	68	-	
Reverse Transfer Capacitance	C_{rss}		-	45	-	
Total Gate Charge	Q_g	$I_D=10A, V_{DS}=30V,$ $V_{GS}=10V$	-	2.3	-	nC
Gate-to-Source Charge	Q_{gs}		-	15.6	-	
Gate-to-Drain ("Miller") Charge	Q_{gd}		-	3.9	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V, V_{DS}=30V,$ $I_D=1A, R_{GEN}=6\Omega$	-	4.6	-	nS
Rise Time	t_r		-	14.8	-	
Turn-Off Delay Time	$t_{d(off)}$		-	26.2	-	
Fall Time	t_f		-	7.8	-	
Gate Resistance	R_g	$f=1\text{MHz}$	-	2.1	4.2	Ω
Source-Drain Ratings and Characteristics						
Continuous Source Current (Body Diode)	I_S	MOSFET symbol showing the integral reverse p-n junction diode.	-	-	5	A
Pulsed Source Current (Body Diode)	I_{SM}		-	-	20	A
Diode Forward Voltage	V_{SD}	$I_S=2A, V_{GS}=0V$	-	1	1.2	V
Reverse Recovery Time	T_{rr}	$T_J=25^\circ\text{C}, I_F=1A,$ $di/dt=100A/\mu s$	-	14	-	nS
Reverse Recovery Charge	Q_{rr}		-	10	-	nC

Notes:

1. Pulse test: Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
2. Repetitive rating; pulse width limited by max. junction temperature.
3. $L=0.1\text{mH}$, $R_g=25\Omega$, $V_{DD}=25V$, $T_J=25^\circ\text{C}$.
4. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch.

Typical Electrical and Thermal Characteristic Curves

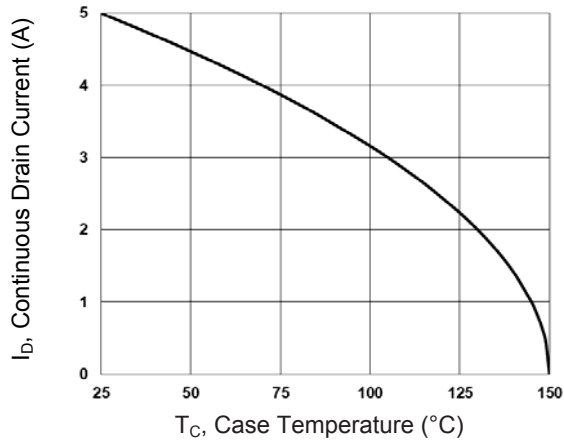


Figure 1. Continuous Drain Current vs. T_C

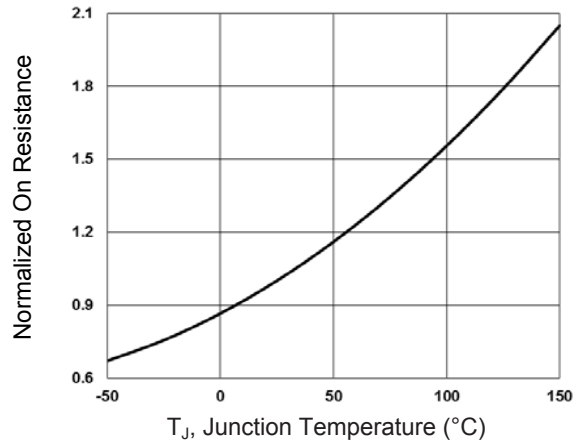


Figure 2. Normalized $R_{DS(ON)}$ vs. T_J

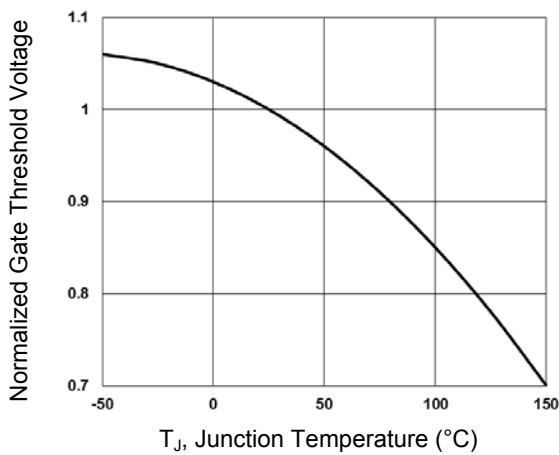


Figure 3. Normalized V_{th} vs. T_J

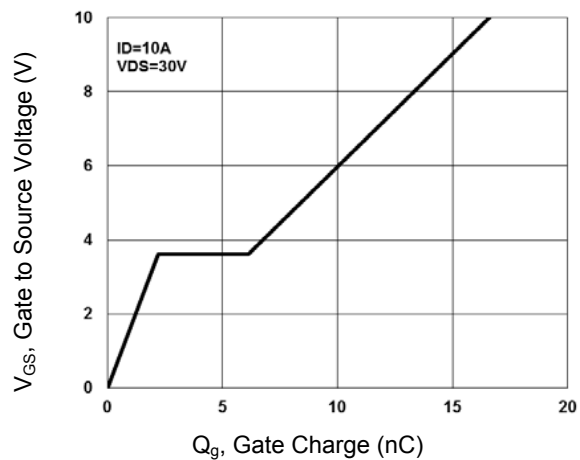


Figure 4. Gate Charge Waveform

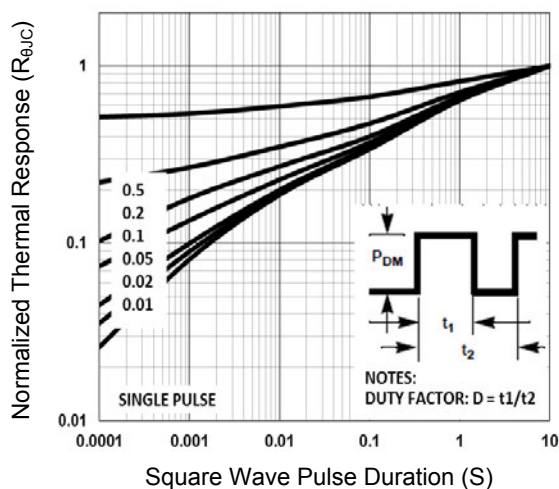


Figure 5. Normalized Transient Impedance

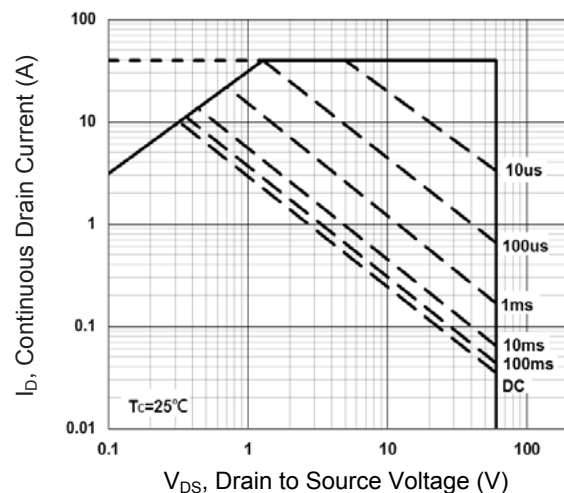
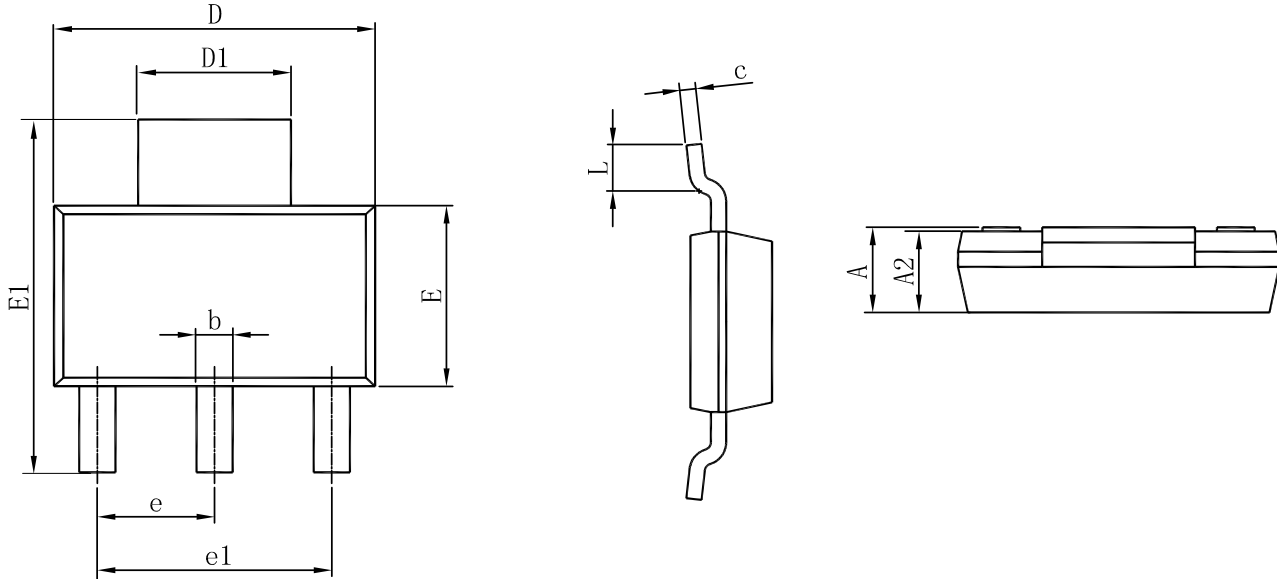


Figure 6. Maximum Safe Operation Area

Package Outline Dimensions (SOT-223)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.50	1.80	0.059	0.071
A2	1.45	1.80	0.057	0.071
b	0.60	0.84	0.024	0.033
c	0.20	0.35	0.008	0.014
D	6.20	6.70	0.244	0.264
D1	2.90	3.10	0.114	0.122
E	3.30	3.70	0.130	0.146
E1	6.70	7.30	0.264	0.287
e	2.30 TYP		0.091 TYP	
e1	4.40	4.70	0.173	0.185
L	0.70	1.10	0.028	0.043

Order Information

Device	Package	Marking	Carrier	Quantity
GSFL6046	SOT-223	L6046	Tape & Reel	3,000Pcs / Reel